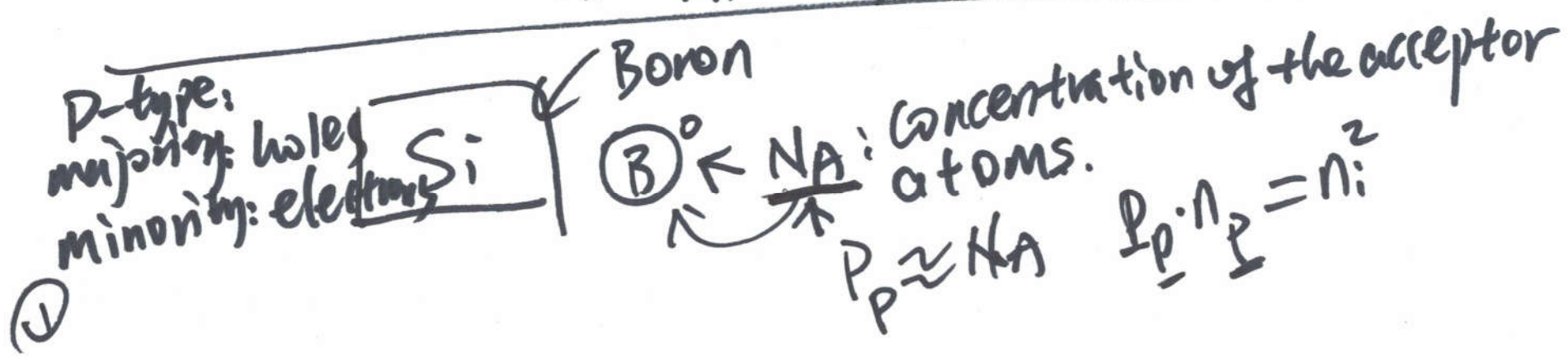


$$\underline{n \cdot p = n_i^2} \Rightarrow \underline{n_n \cdot p_n = n_i^2}$$

$$p_n = \frac{n_i^2}{n_n} = \frac{n_i^2}{N_D}$$



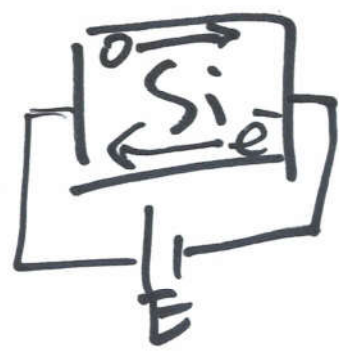
Example:
 n-type Si, dopant Conc. $N_D = 10^{17}/\text{cm}^3$, Find electron
 and hole Conc. at room temp ($T = 300\text{K}$)

$N_D = n_n$, the electron Conc. is $10^{17}/\text{cm}^3$

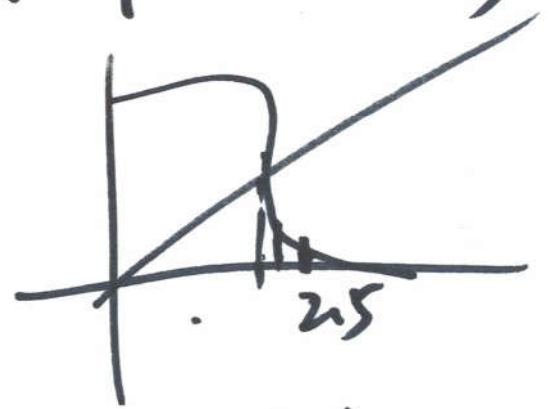
$n_n \cdot p_n = n_i^2$

Conc. of holes $p_n = \frac{n_i^2}{n_n} = \frac{n_i^2}{N_D} = \frac{(1.5 \times 10^{10}/\text{cm}^3)^2}{10^{17}/\text{cm}^3} = 2.25 \times 10^3/\text{cm}^3$

Drift current



$V_{p\text{-drift}} = \mu_p \cdot E \rightarrow$ mobility of holes
 \rightarrow electric field intensity
 $V_{n\text{-drift}} = \mu_n \cdot E$



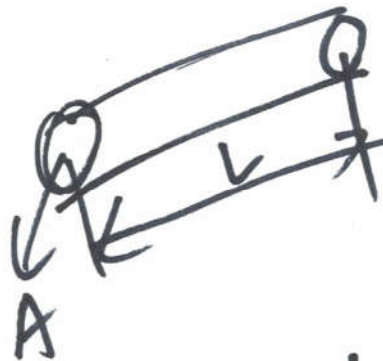
$\mu_n > \mu_p$

electrons move faster/easier than holes.

Resistivity:

$$\rho = \frac{1}{q(\mu_p \cdot p + \mu_n \cdot n)}$$

$\Omega \cdot \text{cm}$



$$R = \rho \cdot \frac{L}{A}$$
$$\rho = \frac{R \cdot A}{L}$$

Conductivity:

$$\sigma = \frac{1}{\rho}$$

magnitude of electron charge (Coulomb, C)

$$1.6 \times 10^{-19} \text{ C}$$

Example: Given: $p = n = n_i = 1.5 \times 10^{10} / \text{cm}^3$, $\mu_n = 1350 \text{ cm}^2 / \text{V} \cdot \text{s}$
 $\mu_p = 480 \text{ cm}^2 / \text{V} \cdot \text{s}$, what is ρ ?

$$\rho = \frac{1}{q(\mu_n \cdot n + \mu_p \cdot p)} = \frac{1}{1.6 \times 10^{-19} \cdot (1350 \text{ cm}^2 / \text{V} \cdot \text{s} \cdot 1.5 \times 10^{10} + 480 \cdot 1.5 \times 10^{10})}$$
$$= 2.28 \times 10^5 \text{ } (\Omega \cdot \text{cm})$$

(3)

Example: p-type, $N_A = 10^{16} / \text{cm}^3$

$\mu_n = 1110 \text{ cm}^2 / \text{v.s.}$, $\mu_p = 400 \text{ cm}^2 / \text{v.s.}$
what is ρ ?

$$\rho = \frac{1}{q(\mu_n n + \mu_p p)}$$

$$n = \frac{n_i^2}{p} = \frac{n_i^2}{N_A}$$

$$= \frac{(1.5 \times 10^{10} / \text{cm}^3)^2}{10^{16} / \text{cm}^3}$$

$$= 2.25 \times 10^4 / \text{cm}^3$$

(4)